

# isc N-Channel Mosfet Transistor

# IRF830A

## FEATURES

- Drain Current  $-I_D=5A@ T_C=25^{\circ}C$
- Drain Source Voltage-  
:  $V_{DSS}= 500V(\text{Min})$
- Fast Switching Speed
- Low Drive Requirement
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

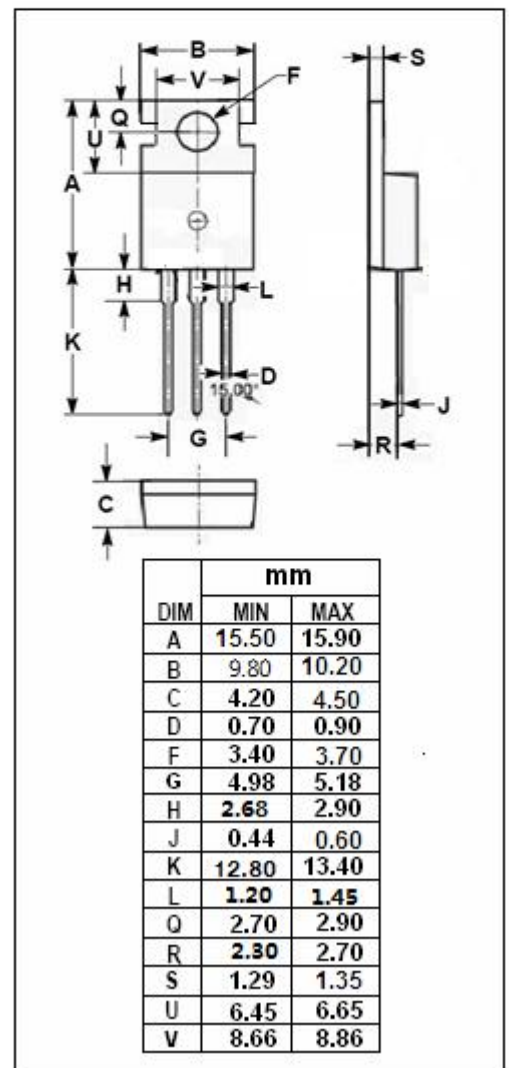
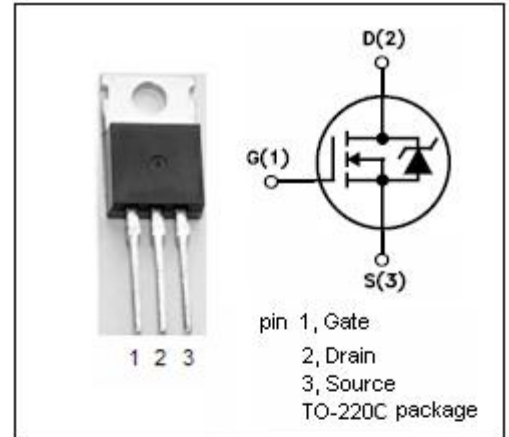
- Switch Mode Power Supply
- Uninterruptable Power Supply
- High speed power switching

## ABSOLUTE MAXIMUM RATINGS( $T_a=25^{\circ}C$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	500	V
$V_{GS}$	Gate-Source Voltage-Continuous	$\pm 30$	V
$I_D$	Drain Current-Continuous@ $T_C=25^{\circ}C$	5	A
	Drain Current-continuous@ $T_C=100^{\circ}C$	3.2	
$I_{DM}$	Drain Current-Single Plused	20	A
$P_D$	Total Dissipation @ $T_C=25^{\circ}C$	74	W
$T_j$	Max. Operating Junction Temperature	150	$^{\circ}C$
$T_{stg}$	Storage Temperature	-55~150	$^{\circ}C$

## • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance,Junction to Case	1.7	$^{\circ}C/W$
$R_{th j-a}$	Thermal Resistance,Junction to Ambient	62	$^{\circ}C/W$



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## ELECTRICAL CHARACTERISTICS

T<sub>C</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	500			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> = 0.25mA	2		4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 3A			1.4	Ω
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±30V; V <sub>DS</sub> = 0			±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 500V; V <sub>GS</sub> =0			25	uA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 5A; V <sub>GS</sub> =0			1.5	V
G <sub>fs</sub>	Forward Transconductance	V <sub>DS</sub> = 50V; I <sub>D</sub> =3A	2.8			S
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =250V; I <sub>D</sub> =5A; R <sub>G</sub> =14Ω		10		ns
t <sub>r</sub>	Rise Time			21		
t <sub>d(off)</sub>	Turn-off Delay Time			21		
t <sub>f</sub>	Fall Time			15		

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